

SHANGHAI SUNRISE ELECTRONICS CO., LTD.

IN4148

SILICON EPITAXIAL PLANAR SWITCHING DIODE

REVERSE VOLTAGE: 75V FORWARD CURRENT: 150mA TECHNICAL SPECIFICATION

FEATURES

- Small glass structure ensures high reliability
- Fast switching
- Low leakage
- High temperature soldering guaranteed: 250°C/10S/9.5mm lead length at 5 lbs tension

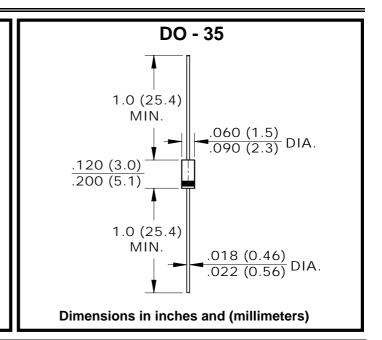
MECHANICAL DATA

 Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C

Case: Glass,hermetically sealed

Polarity: Color band denotes cathode

Mounting position: Any



MAXIMUM RATINGS AND CHARACTERISTICS

(Ratings at 25°C ambient temperature unless otherwise specified)

SYMBOL	\/A111E	
	VALUE	UNITS
V_R	75	V
V_{RM}	100	V
Ι _ο	150	mA
I _{FRM}	300	mA
V_{F}	1	V
	25	nA
'R1	5	μΑ
I_{R2}	50	μА
e 1) Ct	4	pF
e 2) I _F	4	nS
$= 3)$ $R_{\theta}(ja)$	0.35	°C/mW
$T_{STG,}T_{J}$	-55 ∼+175	°C
($\begin{array}{c c} & V_{R} \\ & V_{RM} \\ & I_{O} \\ & I_{FRM} \\ & V_{F} \\ \hline & I_{R1} \\ & I_{R2} \\ e \ 1) & Ct \\ e \ 2) & I_{F} \\ e \ 3) & R_{\theta}(ja) \\ \end{array}$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

Notes:

- 1: V_R=0V, f=1 MHz
- 2: $I_F=10mA$ to $I_R=1mA$, $V_R=6V$, $R_L=100 \Omega$
- 3: Valid provided that leads are kept at ambient temperature at a distance of 8mm from case.